

# ANTREX Electronics

Electronic Components Sourcing Information

---

## Product Reference Information

**Part Number:** BC817K-40VL  
**Manufacturer:** Nexperia USA Inc.  
**Package:** TO-236-3, SC-59, SOT-23-3  
**Availability:** Please confirm with sales

### Product Page:

<https://antrexco.com/product/details/nexperia-usa-inc/bc817k-40vl.html>

### Request a Quote:

[Submit RFQ for this part](#)



Scan for product page

## Contact Information

Email: [info@antrexco.com](mailto:info@antrexco.com)

WhatsApp: +86-186-8066-5326

Website: <https://antrexco.com>

## Quality & Trust

New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

Secure sourcing support for OEM / EMS projects

### Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

---



# BC817K series

45 V, 500 mA NPN general-purpose transistors

Rev. 2 — 6 March 2018

Product data sheet

## 1 Product profile

### 1.1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

| Type number | Package  |          | PNP complement |
|-------------|----------|----------|----------------|
|             | Nexperia | JEDEC    |                |
| BC817K-16   | SOT23    | TO-236AB | BC807K-16      |
| BC817K-25   |          |          | BC807K-25      |
| BC817K-40   |          |          | BC807K-40      |

### 1.2 Features and benefits

- Three current gain selections
- High power dissipation capability
- AEC-Q101 qualified

### 1.3 Applications

- General-purpose switching and amplification

1.4 Quick reference data

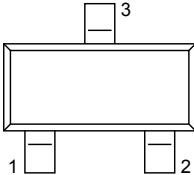
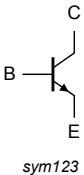
Table 2. Quick reference data  
*T<sub>amb</sub> = 25 °C unless otherwise specified.*

| Symbol           | Parameter                 | Conditions                                     |     | Min | Typ | Max | Unit |
|------------------|---------------------------|------------------------------------------------|-----|-----|-----|-----|------|
| V <sub>CEO</sub> | collector-emitter voltage | open base                                      |     | -   | -   | 45  | V    |
| I <sub>C</sub>   | collector current         |                                                |     | -   | -   | 500 | mA   |
| I <sub>CM</sub>  | peak collector current    | single pulse; t <sub>p</sub> ≤ 1 ms            |     | -   | -   | 1   | A    |
| h <sub>FE</sub>  | DC current gain           | V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA |     |     |     |     |      |
|                  | BC817K-16                 |                                                | [1] | 100 | -   | 250 | -    |
|                  | BC817K-25                 |                                                | [1] | 160 | -   | 400 | -    |
|                  | BC817K-40                 |                                                | [1] | 250 | -   | 600 | -    |

[1] pulsed; t<sub>p</sub> ≤ 300 µs; δ ≤ 0.02

2 Pinning information

Table 3. Pinning

| Pin | Symbol | Description | Simplified outline                                                                   | Graphic symbol                                                                        |
|-----|--------|-------------|--------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| 1   | B      | base        |  |  |
| 2   | E      | emitter     |                                                                                      |                                                                                       |
| 3   | C      | collector   |                                                                                      |                                                                                       |

3 Ordering information

Table 4. Ordering information

| Type number | Package  |                                          |         |
|-------------|----------|------------------------------------------|---------|
|             | Name     | Description                              | Version |
| BC817K-16   | TO-236AB | Plastic surface-mounted package; 3 leads | SOT23   |
| BC817K-25   |          |                                          |         |
| BC817K-40   |          |                                          |         |

## 4 Marking

Table 5. Marking

| Type number | Marking code       |
|-------------|--------------------|
| BC817K-16   | <sup>[1]</sup> HD% |
| BC817K-25   | <sup>[1]</sup> HE% |
| BC817K-40   | <sup>[1]</sup> HF% |

[1] % = placeholder for manufacturing site code

## 5 Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

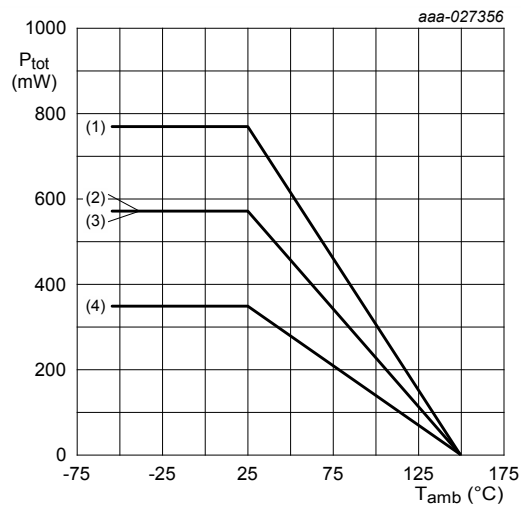
| Symbol    | Parameter                 | Conditions                          | Min | Max | Unit |
|-----------|---------------------------|-------------------------------------|-----|-----|------|
| $V_{CBO}$ | collector-base voltage    | open emitter                        | -   | 50  | V    |
| $V_{CEO}$ | collector-emitter voltage | open base                           | -   | 45  | V    |
| $V_{EBO}$ | emitter-base voltage      | open collector                      | -   | 5   | V    |
| $I_C$     | collector current         |                                     | -   | 500 | mA   |
| $I_{CM}$  | peak collector current    | single pulse; $t_p \leq 1$ ms       | -   | 1   | A    |
| $I_{BM}$  | peak base current         | single pulse; $t_p \leq 1$ ms       | -   | 200 | mA   |
| $P_{tot}$ | total power dissipation   | $T_{amb} \leq 25$ °C <sup>[1]</sup> | -   | 350 | mW   |
|           |                           | <sup>[2]</sup>                      | -   | 575 | mW   |
|           |                           | <sup>[3]</sup>                      | -   | 575 | mW   |
|           |                           | <sup>[4]</sup>                      | -   | 775 | mW   |
| $T_j$     | junction temperature      |                                     | -   | 150 | °C   |
| $T_{amb}$ | ambient temperature       |                                     | -55 | 150 | °C   |
| $T_{stg}$ | storage temperature       |                                     | -65 | 150 | °C   |

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

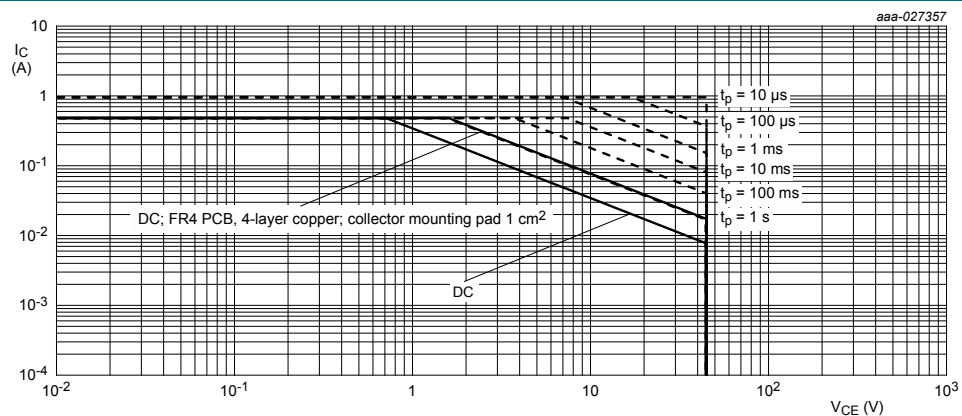
[3] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.

[4] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, 4-layer copper; 1 cm<sup>2</sup>  
 (2) FR4 PCB, single-sided copper; 1 cm<sup>2</sup>  
 (3) FR4 PCB, 4-layer copper; standard footprint  
 (4) FR4 PCB, single-sided copper; standard footprint

**Figure 1. Power derating curves**



FR4 PCB, single-sided copper; standard footprint; single pulse;

$T_{amb} = 25\text{ °C}$

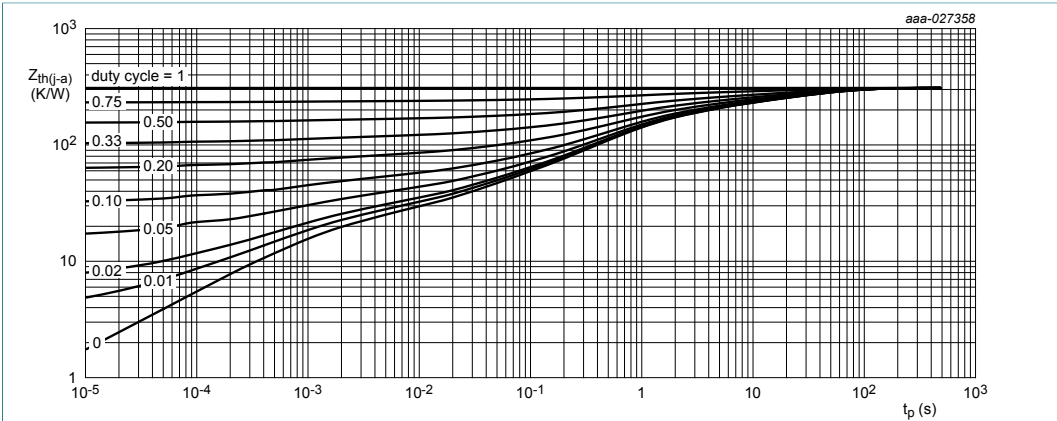
**Figure 2. Safe operating area; junction to ambient; continuous and peak collector currents as a function of collector-emitter voltage**

6 Thermal characteristics

Table 7. Thermal characteristics

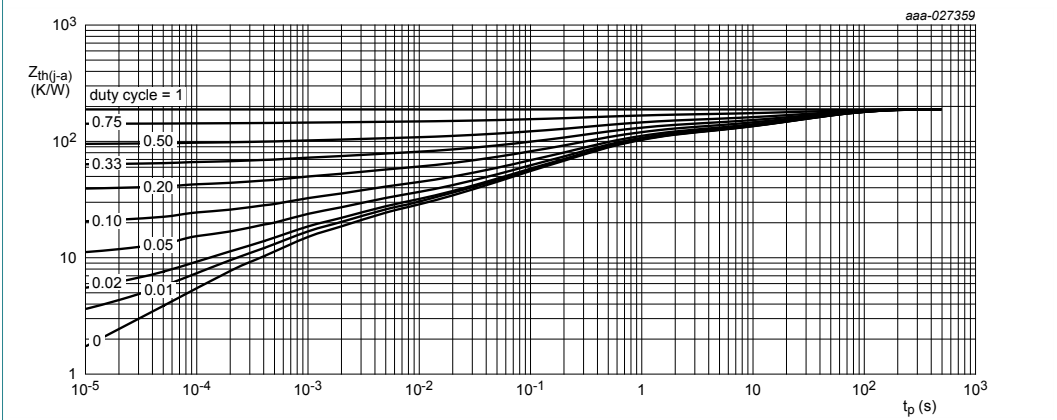
| Symbol         | Parameter                                        | Conditions  |     | Min | Typ | Max | Unit |
|----------------|--------------------------------------------------|-------------|-----|-----|-----|-----|------|
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] | -   | -   | 358 | K/W  |
|                |                                                  |             | [2] | -   | -   | 218 | K/W  |
|                |                                                  |             | [3] | -   | -   | 218 | K/W  |
|                |                                                  |             | [4] | -   | -   | 162 | K/W  |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             |     | -   | -   | 60  | K/W  |

[1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.  
[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.  
[3] Device mounted on an FR4 PCB; 4-layer copper; tin-plated and standard footprint.  
[4] Device mounted on an FR4 PCB; 4-layer copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



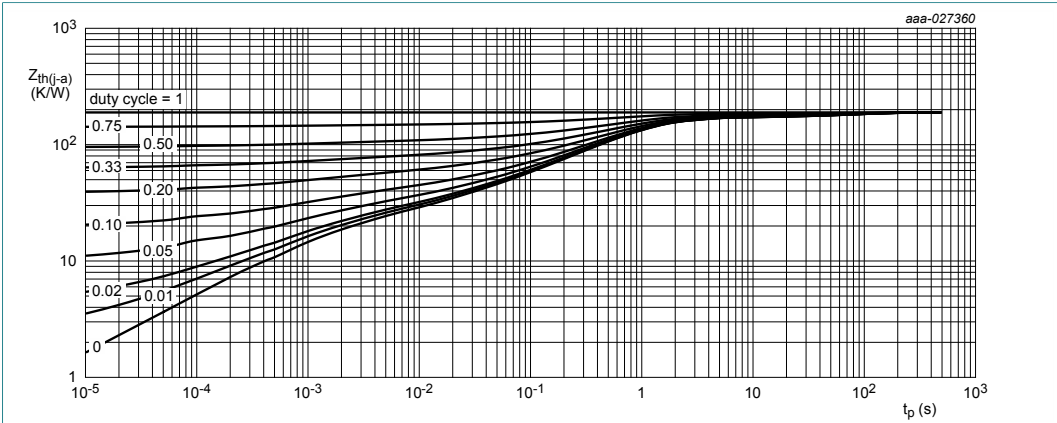
FR4 PCB; single-sided copper; tin-plated and standard footprint

Figure 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



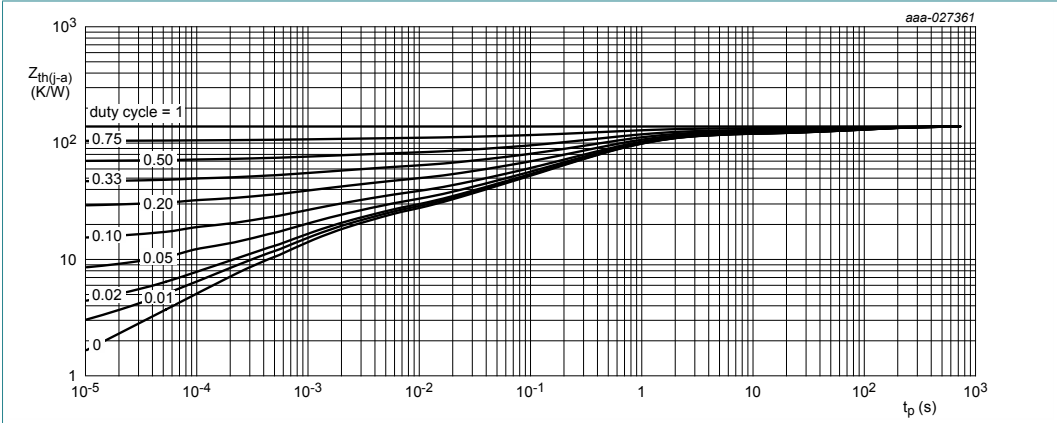
FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>

Figure 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin plated and standard footprint

Figure 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin plated; mounting pad for collector 1 cm<sup>2</sup>

Figure 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

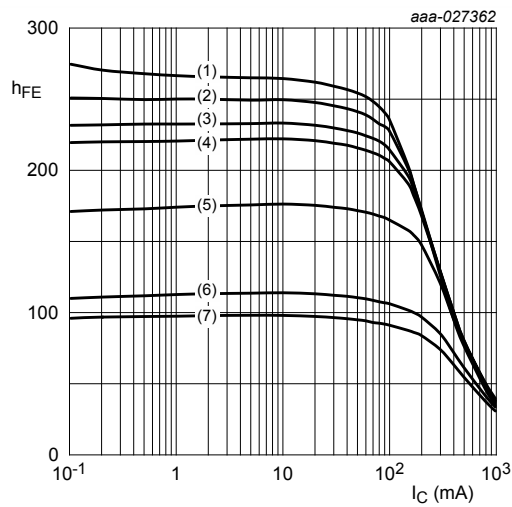
## 7 Characteristics

**Table 8. Characteristics**

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

| Symbol        | Parameter                            | Conditions                                                                        |     | Min | Typ | Max | Unit          |
|---------------|--------------------------------------|-----------------------------------------------------------------------------------|-----|-----|-----|-----|---------------|
| $V_{(BR)CBO}$ | collector-base breakdown voltage     | $I_C = 100\text{ }\mu\text{A}$ ; $I_E = 0\text{ A}$                               |     | 50  | -   | -   | V             |
| $V_{(BR)CEO}$ | collector-emitter breakdown voltage  | $I_C = 10\text{ mA}$ ; $I_B = 0\text{ A}$                                         |     | 45  | -   | -   | V             |
| $V_{(BR)EBO}$ | emitter-base breakdown voltage       | $I_E = 100\text{ }\mu\text{A}$ ; $I_C = 0\text{ A}$                               |     | 5   | -   | -   | V             |
| $I_{CBO}$     | collector-base cut-off current       | $V_{CB} = 25\text{ V}$ ; $I_E = 0\text{ A}$                                       |     | -   | -   | 100 | nA            |
|               |                                      | $V_{CB} = 25\text{ V}$ ; $I_E = 0\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ |     | -   | -   | 5   | $\mu\text{A}$ |
| $I_{EBO}$     | emitter-base cut-off current         | $V_{EB} = 5\text{ V}$ ; $I_C = 0\text{ A}$                                        |     | -   | -   | 100 | nA            |
| $h_{FE}$      | DC current gain                      |                                                                                   |     |     |     |     |               |
|               | BC817K-16                            | $V_{CE} = 1\text{ V}$ ; $I_C = 100\text{ mA}$                                     | [1] | 100 | -   | 250 |               |
|               | BC817K-25                            | $V_{CE} = 1\text{ V}$ ; $I_C = 100\text{ mA}$                                     | [1] | 160 | -   | 400 |               |
|               | BC817K-40                            | $V_{CE} = 1\text{ V}$ ; $I_C = 100\text{ mA}$                                     | [1] | 250 | -   | 600 |               |
|               | BC817K-16, -25, -40                  | $V_{CE} = 1\text{ V}$ ; $I_C = 500\text{ mA}$                                     | [1] | 40  | -   | -   |               |
| $V_{CEsat}$   | collector-emitter saturation voltage | $I_C = 500\text{ mA}$ ; $I_B = 50\text{ mA}$                                      | [1] | -   | -   | 700 | mV            |
| $V_{BEsat}$   | base-emitter saturation voltage      | $I_C = 500\text{ mA}$ ; $I_B = 50\text{ mA}$                                      | [1] | -   | -   | 1.2 | V             |
| $V_{BE}$      | base-emitter voltage                 | $V_{CE} = 1\text{ V}$ ; $I_C = 500\text{ mA}$                                     | [1] | -   | -   | 1.2 | V             |
| $f_T$         | transition frequency                 | $V_{CE} = 5\text{ V}$ ; $I_C = 10\text{ mA}$ ; $f = 100\text{ MHz}$               |     | 100 | -   | -   | MHz           |
| $C_c$         | collector capacitance                | $V_{CB} = 10\text{ V}$ ; $I_E = i_e = 0\text{ A}$ ; $f = 1\text{ MHz}$            |     | -   | 3   | -   | pF            |
| $C_e$         | emitter capacitance                  | $V_{EB} = 0.5\text{ V}$ ; $I_C = i_c = 0\text{ A}$ ; $f = 1\text{ MHz}$           |     |     |     |     |               |
|               | BC817K-16                            |                                                                                   |     | -   | 44  | -   | pF            |
|               | BC817K-25                            |                                                                                   |     | -   | 39  | -   | pF            |
|               | BC817K-40                            |                                                                                   |     | -   | 39  | -   | pF            |

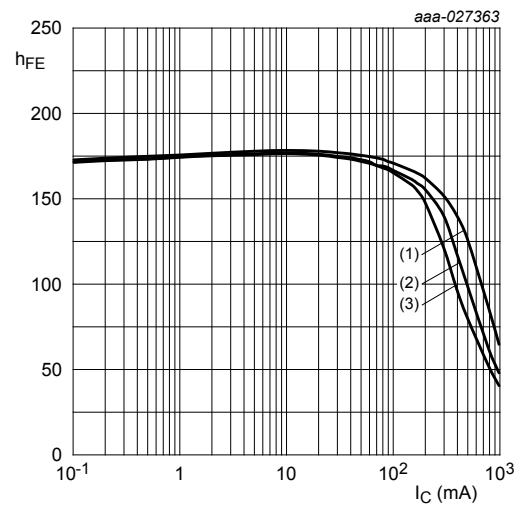
[1] pulsed;  $t_p \leq 300\text{ }\mu\text{s}$ ;  $\delta \leq 0.02$



$V_{CE} = 1 \text{ V}$

- (1)  $T_{amb} = 150 \text{ }^{\circ}\text{C}$
- (2)  $T_{amb} = 125 \text{ }^{\circ}\text{C}$
- (3)  $T_{amb} = 100 \text{ }^{\circ}\text{C}$
- (4)  $T_{amb} = 85 \text{ }^{\circ}\text{C}$
- (5)  $T_{amb} = 25 \text{ }^{\circ}\text{C}$
- (6)  $T_{amb} = -40 \text{ }^{\circ}\text{C}$
- (7)  $T_{amb} = -55 \text{ }^{\circ}\text{C}$

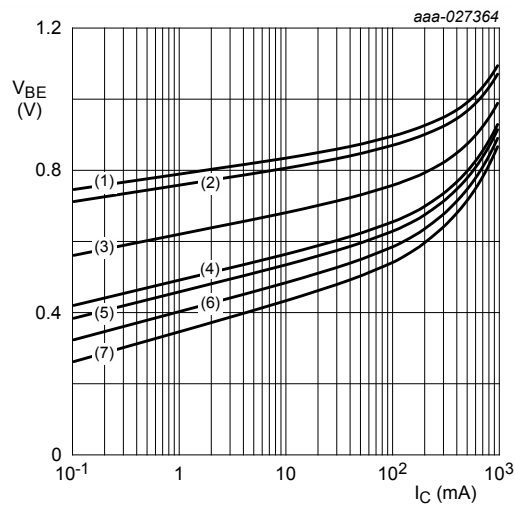
**Figure 7. BC817K-16: DC current gain as a function of collector current; typical values**



$T_{amb} = 25 \text{ }^{\circ}\text{C}$

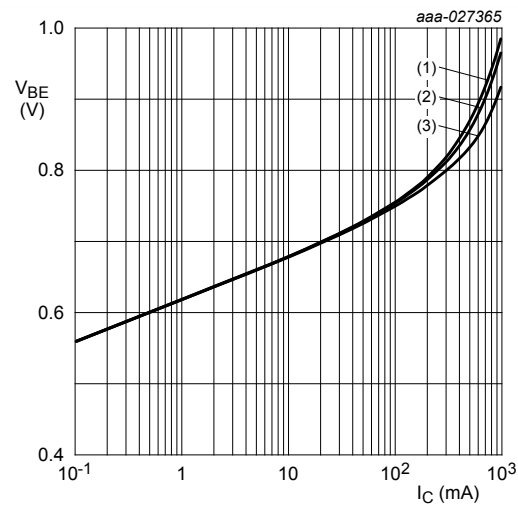
- (1)  $V_{CE} = 5 \text{ V}$
- (2)  $V_{CE} = 2 \text{ V}$
- (3)  $V_{CE} = 1 \text{ V}$

**Figure 8. BC817K-16: DC current gain as a function of collector current; typical values**



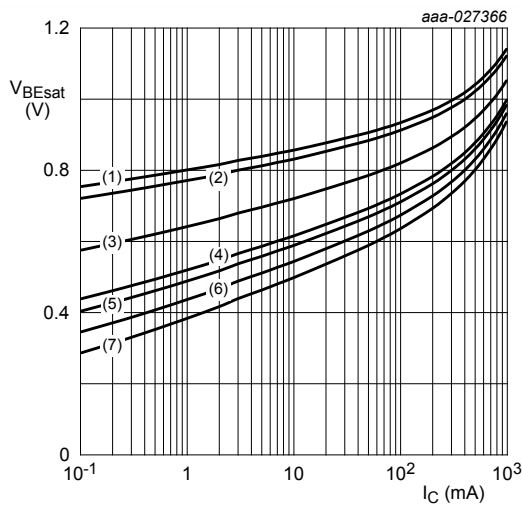
- $V_{CE} = 1\text{ V}$
- (1)  $T_{amb} = -55\text{ °C}$
  - (2)  $T_{amb} = -40\text{ °C}$
  - (3)  $T_{amb} = 25\text{ °C}$
  - (4)  $T_{amb} = 85\text{ °C}$
  - (5)  $T_{amb} = 100\text{ °C}$
  - (6)  $T_{amb} = 125\text{ °C}$
  - (7)  $T_{amb} = 150\text{ °C}$

Figure 9. BC817K-16: Base-emitter voltage as a function of collector current; typical values



- $T_{amb} = 25\text{ °C}$
- (1)  $V_{CE} = 1\text{ V}$
  - (2)  $V_{CE} = 2\text{ V}$
  - (3)  $V_{CE} = 5\text{ V}$

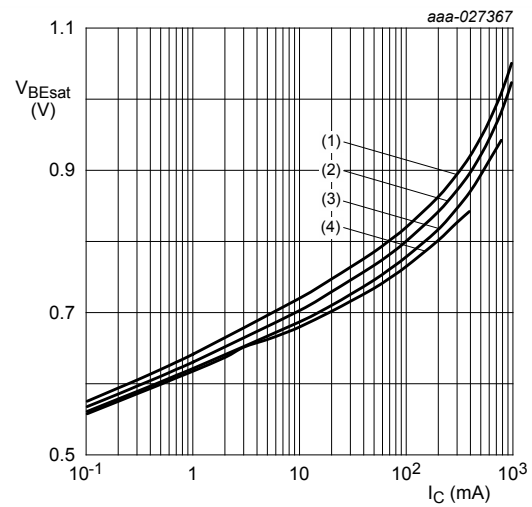
Figure 10. BC817K-16: Base-emitter voltage as a function of collector current; typical values



$I_C/I_B = 10$

- (1)  $T_{amb} = -55\text{ °C}$
- (2)  $T_{amb} = -40\text{ °C}$
- (3)  $T_{amb} = 25\text{ °C}$
- (4)  $T_{amb} = 85\text{ °C}$
- (5)  $T_{amb} = 100\text{ °C}$
- (6)  $T_{amb} = 125\text{ °C}$
- (7)  $T_{amb} = 150\text{ °C}$

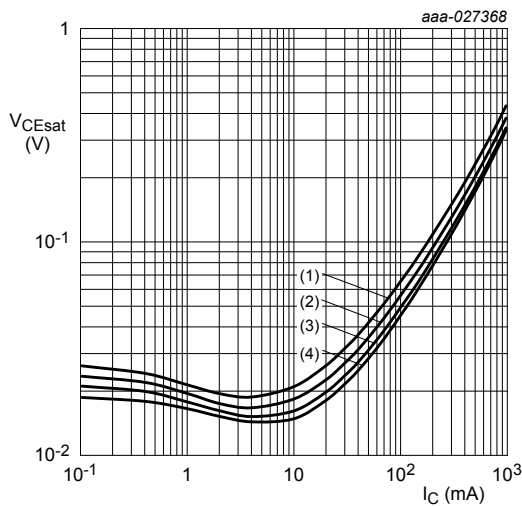
**Figure 11. BC817K-16: Base-emitter saturation voltage as a function of collector current; typical values**



$T_{amb} = 25\text{ °C}$

- (1)  $I_C/I_B = 10$
- (2)  $I_C/I_B = 20$
- (3)  $I_C/I_B = 50$
- (4)  $I_C/I_B = 100$

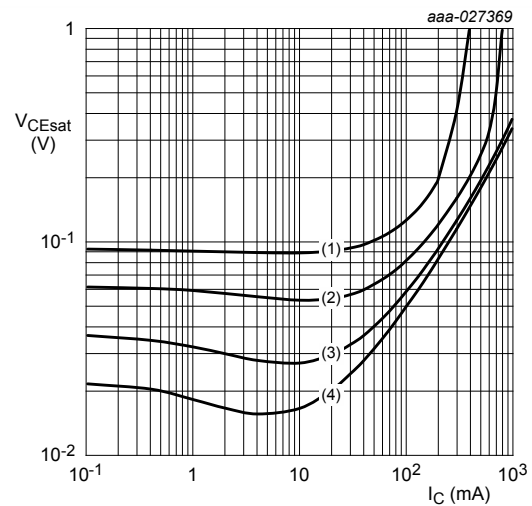
**Figure 12. BC817K-16: Base-emitter saturation voltage as a function of collector current; typical values**



$I_C/I_B = 10$

- (1)  $T_{amb} = 150\text{ °C}$
- (2)  $T_{amb} = 85\text{ °C}$
- (3)  $T_{amb} = 25\text{ °C}$
- (4)  $T_{amb} = -40\text{ °C}$

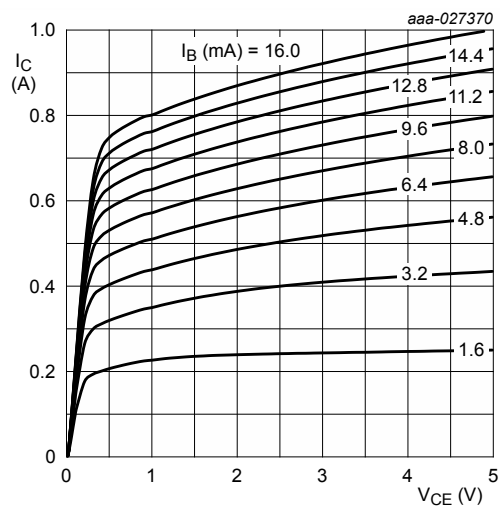
**Figure 13. BC817K-16: Collector-emitter saturation voltage as a function of collector current; typical values**



$T_{amb} = 25\text{ °C}$

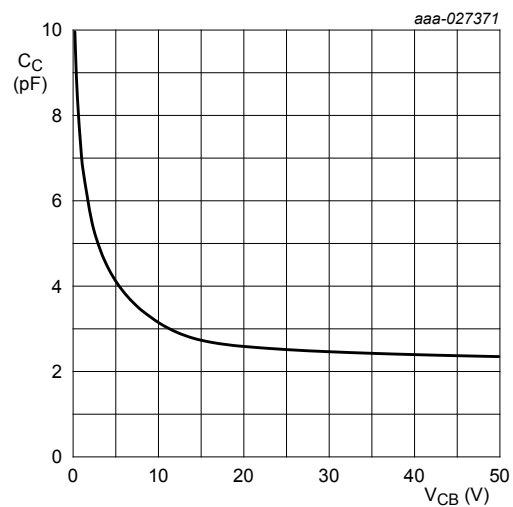
- (1)  $I_C/I_B = 100$
- (2)  $I_C/I_B = 50$
- (3)  $I_C/I_B = 20$
- (4)  $I_C/I_B = 10$

**Figure 14. BC817K-16: Collector-emitter saturation voltage as a function of collector current; typical values**



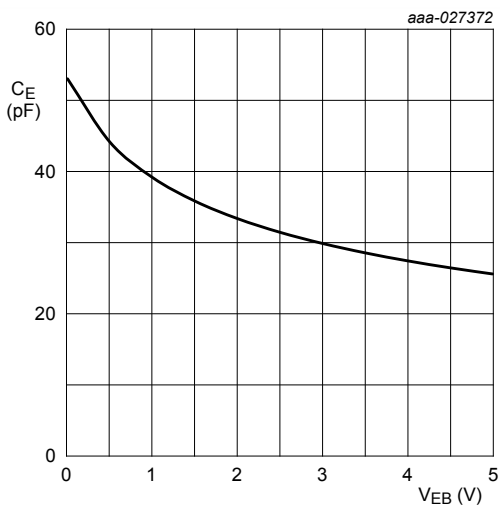
$T_{amb} = 25\text{ }^{\circ}\text{C}$

Figure 15. BC817K-16: Collector current as a function of collector-emitter voltage; typical values



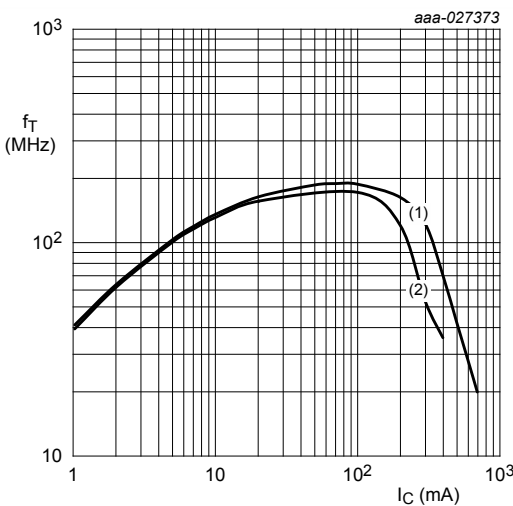
$f = 1\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

Figure 16. BC817K-16: Collector capacitance as a function of collector-base voltage; typical values



$f = 1\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

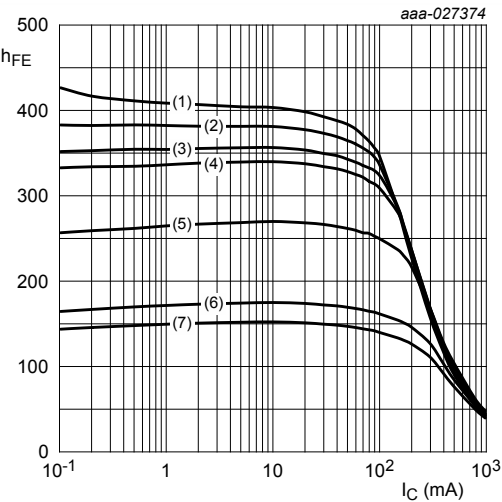
Figure 17. BC817K-16: Emitter capacitance as a function of emitter-base voltage; typical values



$f = 100\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

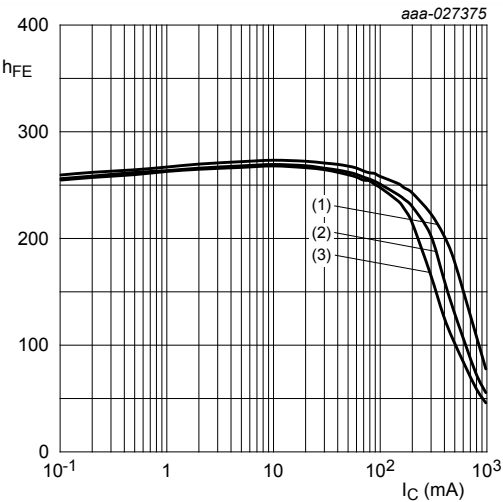
- (1)  $V_{CE} = 5\text{ V}$
- (2)  $V_{CE} = 1\text{ V}$

Figure 18. BC817K-16: Transition frequency as a function of collector current voltage; typical values



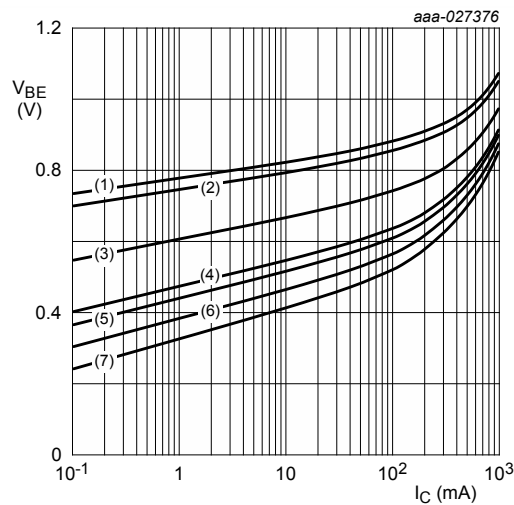
- $V_{CE} = 1$  V
- (1)  $T_{amb} = 150$  °C
  - (2)  $T_{amb} = 125$  °C
  - (3)  $T_{amb} = 100$  °C
  - (4)  $T_{amb} = 85$  °C
  - (5)  $T_{amb} = 25$  °C
  - (6)  $T_{amb} = -40$  °C
  - (7)  $T_{amb} = -55$  °C

Figure 19. BC817K-25: DC current gain as a function of collector current; typical values



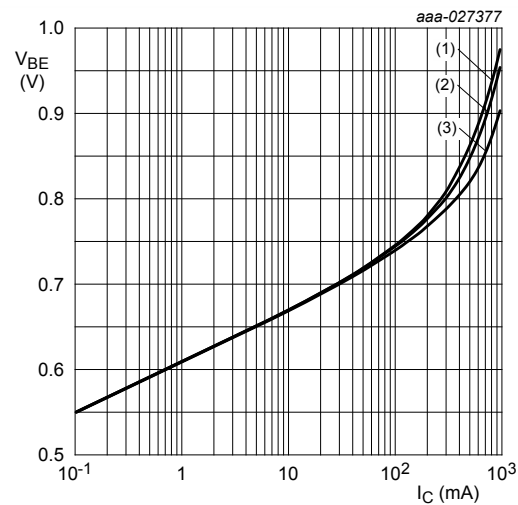
- $T_{amb} = 25$  °C
- (1)  $V_{CE} = 5$  V
  - (2)  $V_{CE} = 2$  V
  - (3)  $V_{CE} = 1$  V

Figure 20. BC817K-25: DC current gain as a function of collector current; typical values



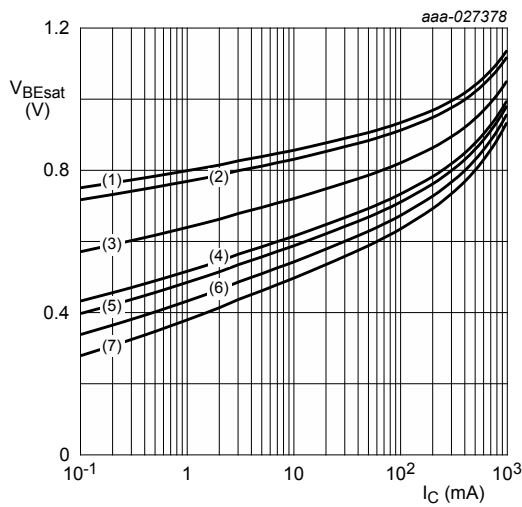
- $V_{CE} = 1\text{ V}$
- (1)  $T_{amb} = -55^\circ\text{C}$
  - (2)  $T_{amb} = -40^\circ\text{C}$
  - (3)  $T_{amb} = 25^\circ\text{C}$
  - (4)  $T_{amb} = 85^\circ\text{C}$
  - (5)  $T_{amb} = 100^\circ\text{C}$
  - (6)  $T_{amb} = 125^\circ\text{C}$
  - (7)  $T_{amb} = 150^\circ\text{C}$

Figure 21. BC817K-25: Base-emitter voltage as a function of collector current; typical values



- $T_{amb} = 25^\circ\text{C}$
- (1)  $V_{CE} = 1\text{ V}$
  - (2)  $V_{CE} = 2\text{ V}$
  - (3)  $V_{CE} = 5\text{ V}$

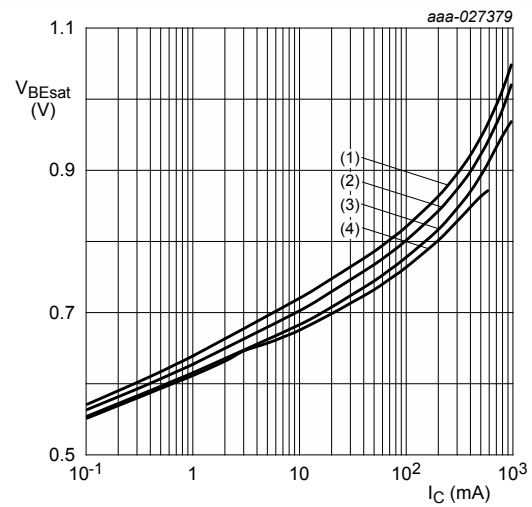
Figure 22. BC817K-25: Base-emitter voltage as a function of collector current; typical values



$$I_C/I_B = 10$$

- (1)  $T_{amb} = -55\text{ °C}$
- (2)  $T_{amb} = -40\text{ °C}$
- (3)  $T_{amb} = 25\text{ °C}$
- (4)  $T_{amb} = 85\text{ °C}$
- (5)  $T_{amb} = 100\text{ °C}$
- (6)  $T_{amb} = 125\text{ °C}$
- (7)  $T_{amb} = 150\text{ °C}$

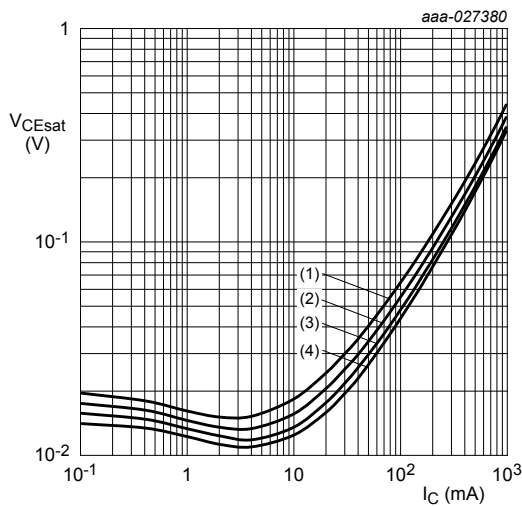
**Figure 23. BC817K-25: Base-emitter saturation voltage as a function of collector current; typical values**



$$T_{amb} = 25\text{ °C}$$

- (1)  $I_C/I_B = 10$
- (2)  $I_C/I_B = 20$
- (3)  $I_C/I_B = 50$
- (4)  $I_C/I_B = 100$

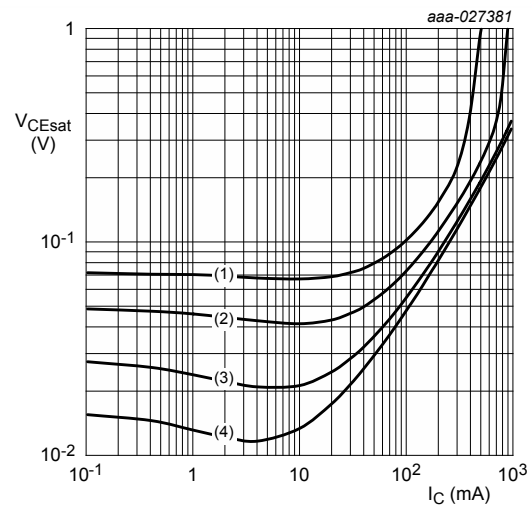
**Figure 24. BC817K-25: Base-emitter saturation voltage as a function of collector current; typical values**



$$I_C/I_B = 10$$

- (1)  $T_{amb} = 150\text{ °C}$
- (2)  $T_{amb} = 85\text{ °C}$
- (3)  $T_{amb} = 25\text{ °C}$
- (4)  $T_{amb} = -40\text{ °C}$

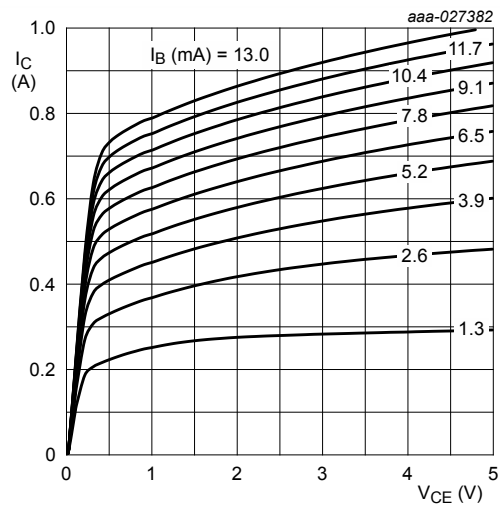
**Figure 25. BC817K-25: Collector-emitter saturation voltage as a function of collector current; typical values**



$$T_{amb} = 25\text{ °C}$$

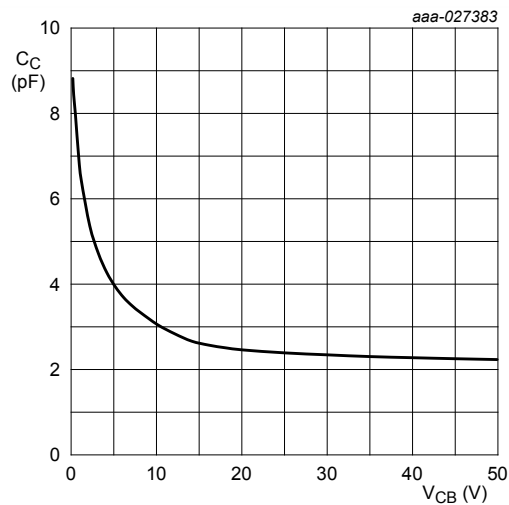
- (1)  $I_C/I_B = 100$
- (2)  $I_C/I_B = 50$
- (3)  $I_C/I_B = 20$
- (4)  $I_C/I_B = 10$

**Figure 26. BC817K-25: Collector-emitter saturation voltage as a function of collector current; typical values**



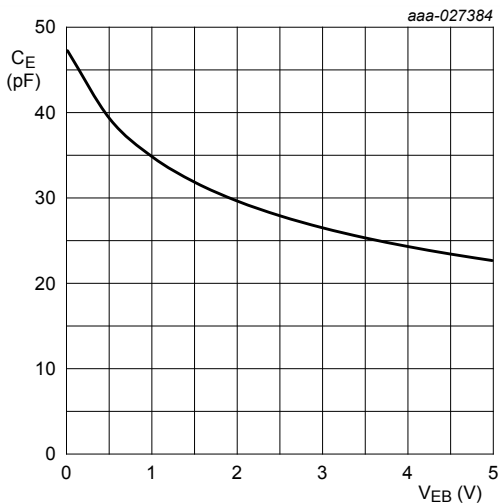
$T_{amb} = 25^\circ\text{C}$

Figure 27. BC817K-25: Collector current as a function of collector-emitter voltage; typical values



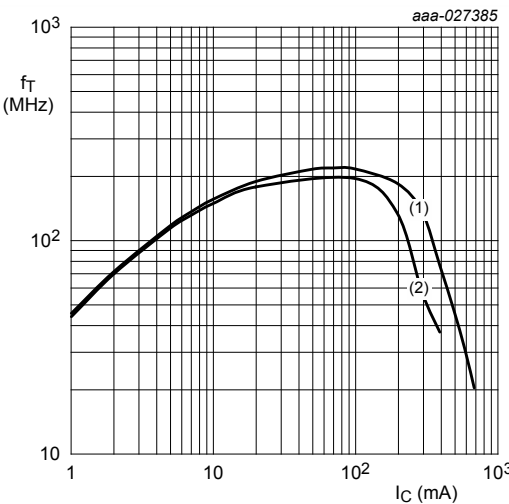
$f = 1$  MHz;  $T_{amb} = 25^\circ\text{C}$

Figure 28. BC817K-25: Collector capacitance as a function of collector-base voltage; typical values



$f = 1$  MHz;  $T_{amb} = 25^\circ\text{C}$

Figure 29. BC817K-25: Emitter capacitance as a function of emitter-base voltage; typical values

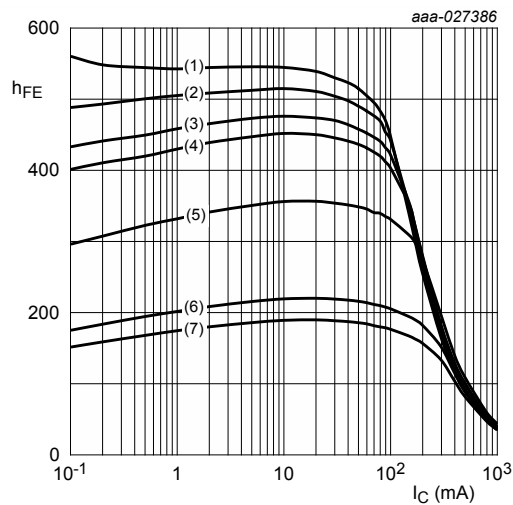


$f = 100$  MHz;  $T_{amb} = 25^\circ\text{C}$

(1)  $V_{CE} = 5$  V

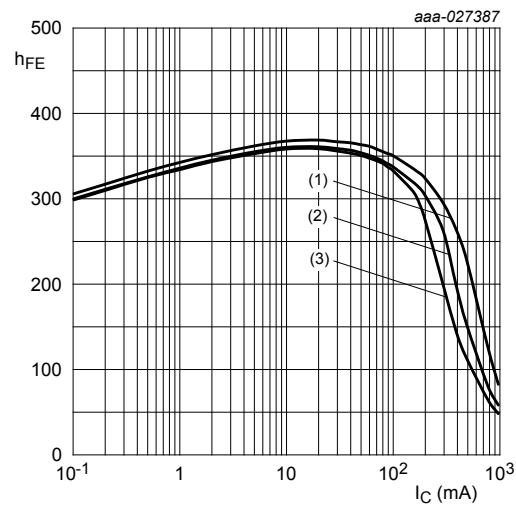
(2)  $V_{CE} = 1$  V

Figure 30. BC817K-25: Transition frequency as a function of collector current voltage; typical values



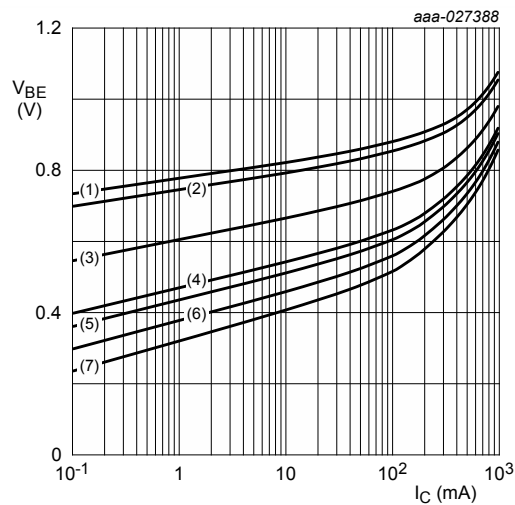
- $V_{CE} = 1$  V
- (1)  $T_{amb} = 150$  °C
  - (2)  $T_{amb} = 125$  °C
  - (3)  $T_{amb} = 100$  °C
  - (4)  $T_{amb} = 85$  °C
  - (5)  $T_{amb} = 25$  °C
  - (6)  $T_{amb} = -40$  °C
  - (7)  $T_{amb} = -55$  °C

Figure 31. BC817K-40: DC current gain as a function of collector current; typical values



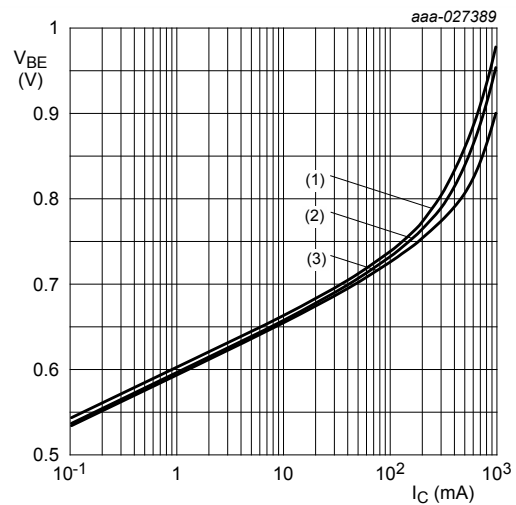
- $T_{amb} = 25$  °C
- (1)  $V_{CE} = 5$  V
  - (2)  $V_{CE} = 2$  V
  - (3)  $V_{CE} = 1$  V

Figure 32. BC817K-40: DC current gain as a function of collector current; typical values



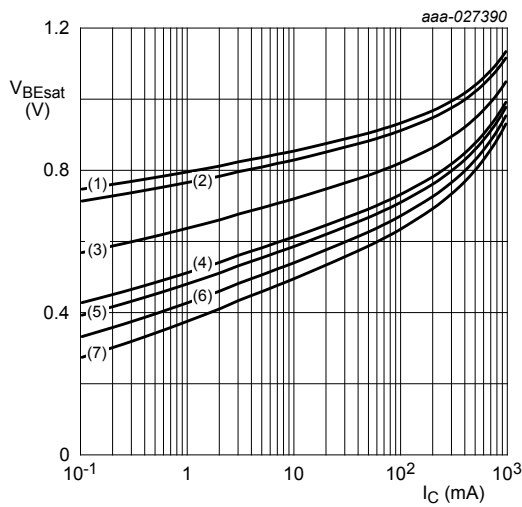
- $V_{CE} = 1\text{ V}$
- (1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$
  - (2)  $T_{amb} = -40\text{ }^{\circ}\text{C}$
  - (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$
  - (4)  $T_{amb} = 85\text{ }^{\circ}\text{C}$
  - (5)  $T_{amb} = 100\text{ }^{\circ}\text{C}$
  - (6)  $T_{amb} = 125\text{ }^{\circ}\text{C}$
  - (7)  $T_{amb} = 150\text{ }^{\circ}\text{C}$

Figure 33. BC817K-40: Base-emitter voltage as a function of collector current; typical values



- $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (1)  $V_{CE} = 1\text{ V}$
  - (2)  $V_{CE} = 2\text{ V}$
  - (3)  $V_{CE} = 5\text{ V}$

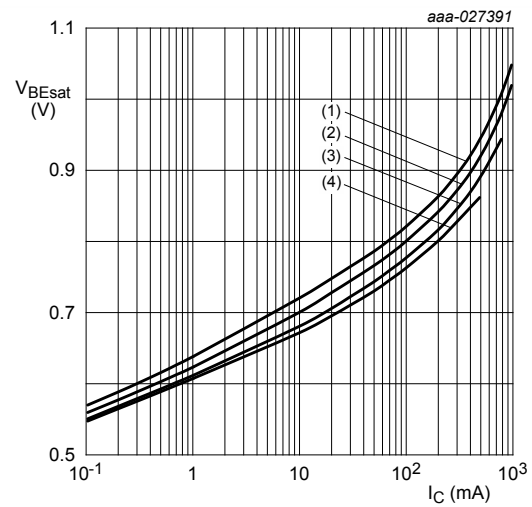
Figure 34. BC817K-40: Base-emitter voltage as a function of collector current; typical values



$$I_C/I_B = 10$$

- (1)  $T_{amb} = -55\text{ °C}$
- (2)  $T_{amb} = -40\text{ °C}$
- (3)  $T_{amb} = 25\text{ °C}$
- (4)  $T_{amb} = 85\text{ °C}$
- (5)  $T_{amb} = 100\text{ °C}$
- (6)  $T_{amb} = 125\text{ °C}$
- (7)  $T_{amb} = 150\text{ °C}$

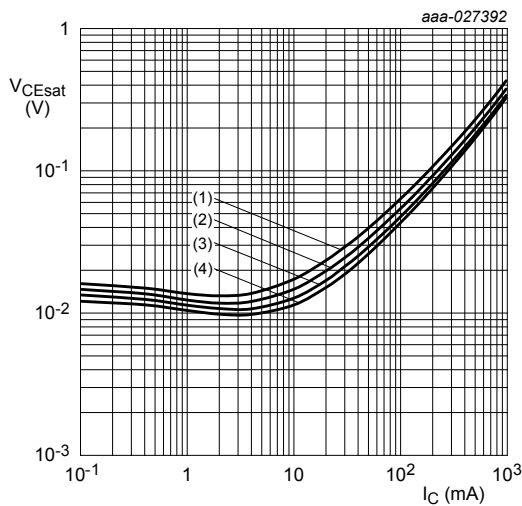
**Figure 35. BC817K-40: Base-emitter saturation voltage as a function of collector current; typical values**



$$T_{amb} = 25\text{ °C}$$

- (1)  $I_C/I_B = 10$
- (2)  $I_C/I_B = 20$
- (3)  $I_C/I_B = 50$
- (4)  $I_C/I_B = 100$

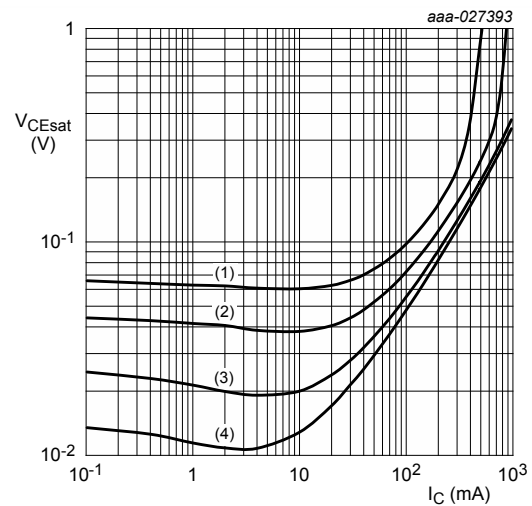
**Figure 36. BC817K-40: Base-emitter saturation voltage as a function of collector current; typical values**



$$I_C/I_B = 10$$

- (1)  $T_{amb} = 150\text{ °C}$
- (2)  $T_{amb} = 85\text{ °C}$
- (3)  $T_{amb} = 25\text{ °C}$
- (4)  $T_{amb} = -40\text{ °C}$

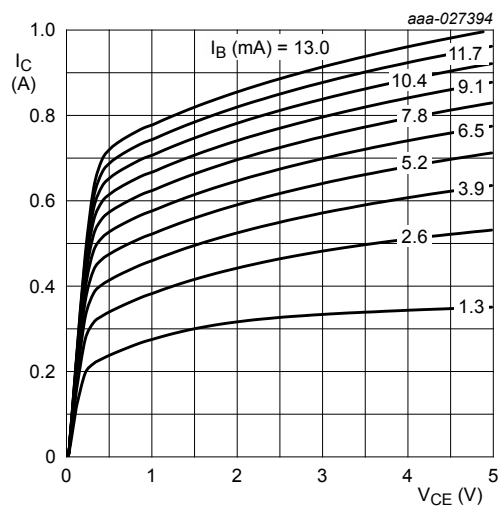
**Figure 37. BC817K-40: Collector-emitter saturation voltage as a function of collector current; typical values**



$$T_{amb} = 25\text{ °C}$$

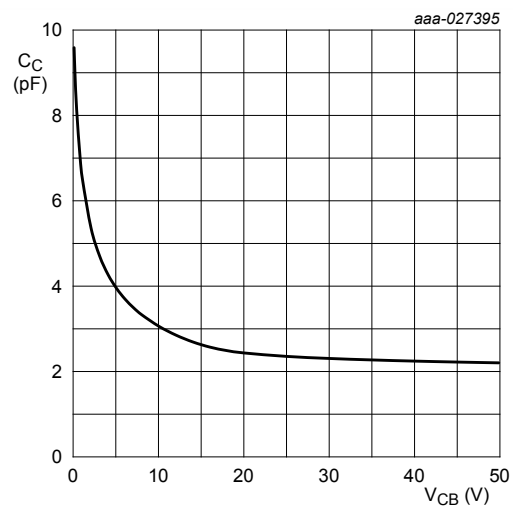
- (1)  $I_C/I_B = 100$
- (2)  $I_C/I_B = 50$
- (3)  $I_C/I_B = 20$
- (4)  $I_C/I_B = 10$

**Figure 38. BC817K-40: Collector-emitter saturation voltage as a function of collector current; typical values**



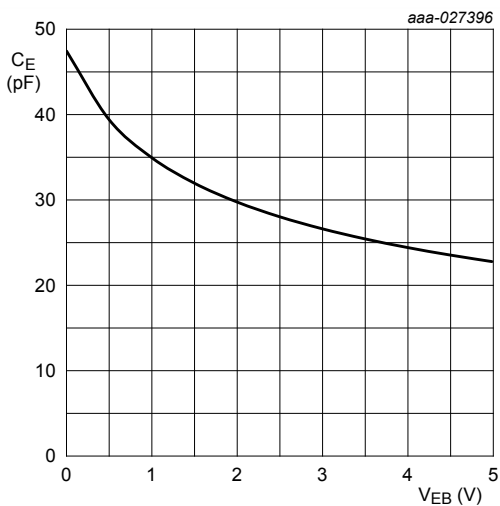
$T_{amb} = 25\text{ }^{\circ}\text{C}$

Figure 39. BC817K-40: Collector current as a function of collector-emitter voltage; typical values



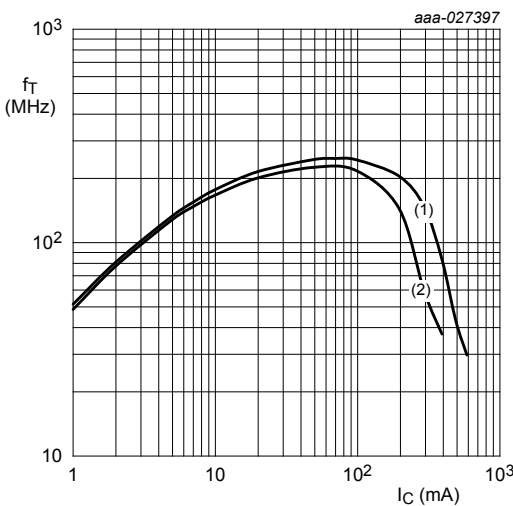
$f = 1\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

Figure 40. BC817K-40: Collector capacitance as a function of collector-base voltage; typical values



$f = 1\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

Figure 41. BC817K-40: Emitter capacitance as a function of emitter-base voltage; typical values



$f = 100\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

- (1)  $V_{CE} = 5\text{ V}$
- (2)  $V_{CE} = 1\text{ V}$

Figure 42. BC817K-40: Transition frequency as a function of collector current voltage; typical values

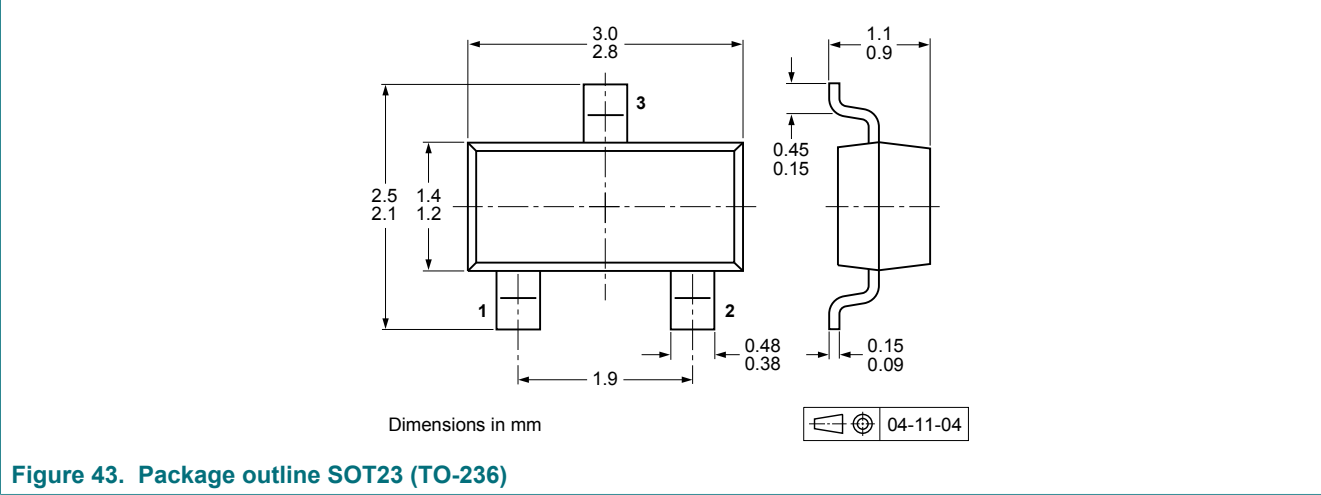
## 8 Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

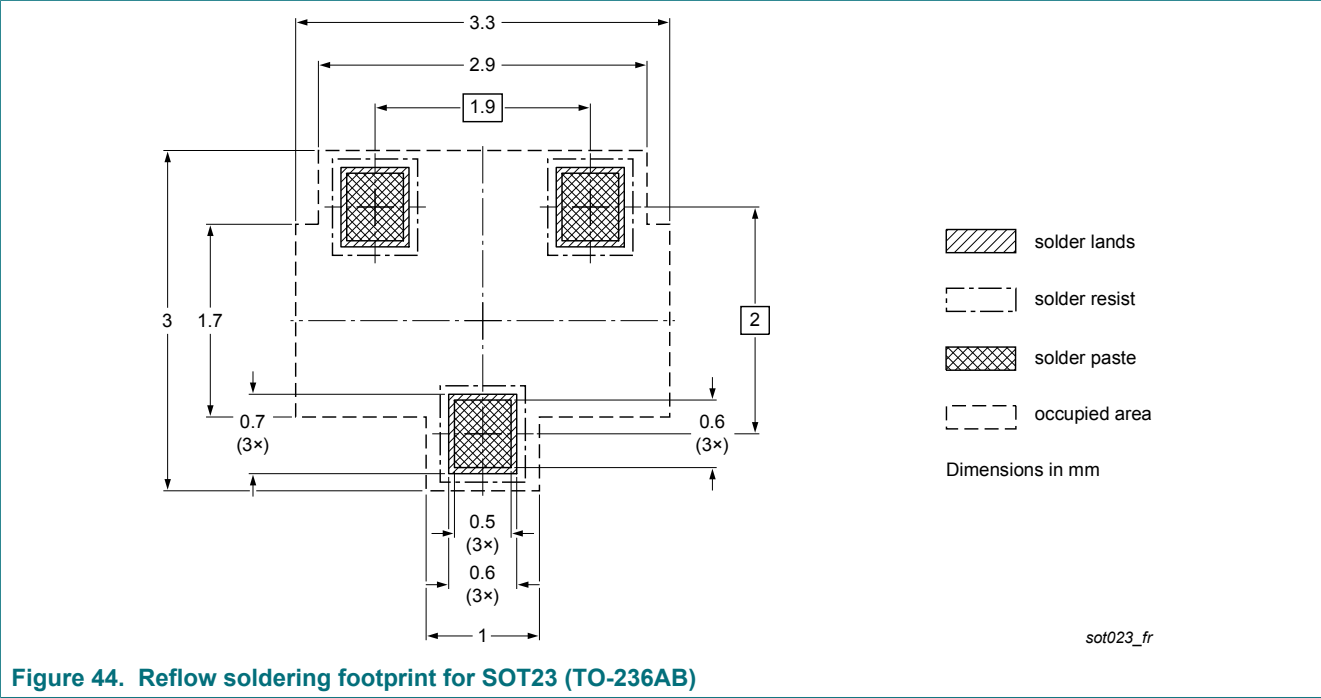
9 Package outline

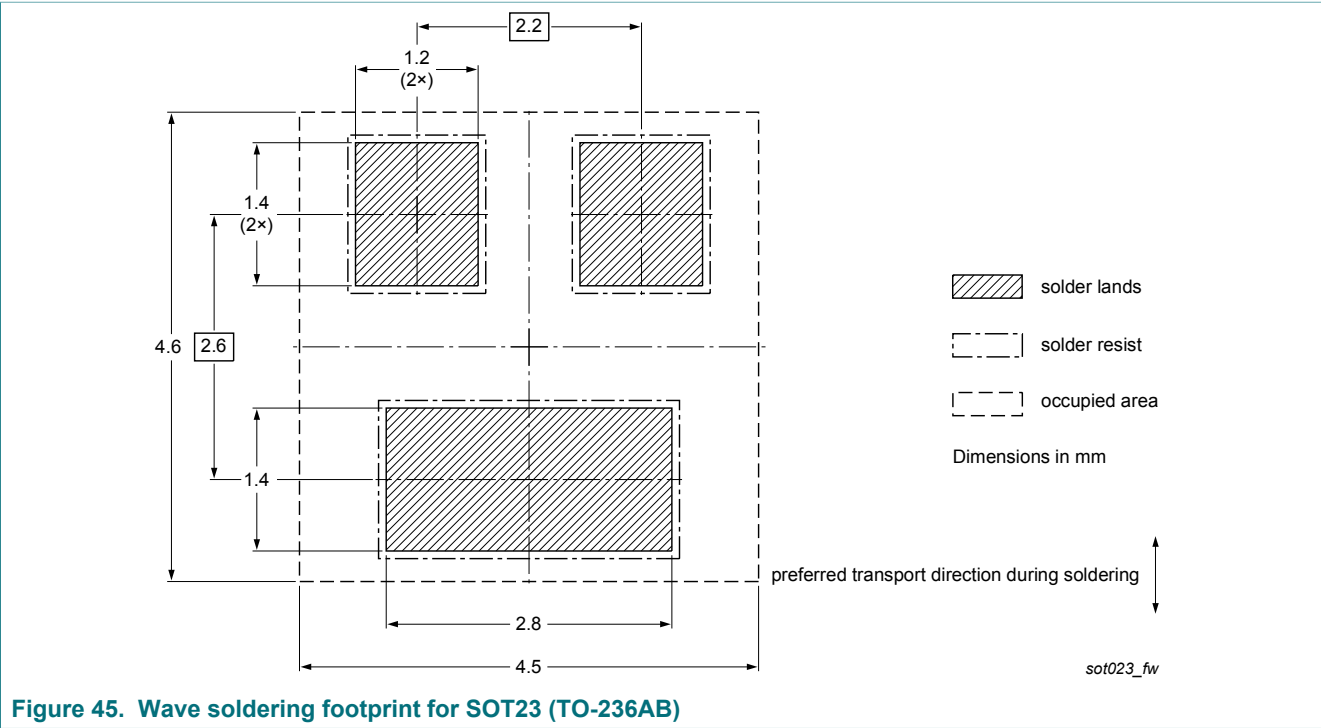
Table 9. Package outline



10 Soldering

Table 10. Soldering





11 Revision history

Table 11. Revision history

| Document ID    | Release date                           | Data sheet status  |  | Supersedes     |
|----------------|----------------------------------------|--------------------|--|----------------|
| BC817K_SER v.2 | 20180306                               | Product data sheet |  | BC817K_SER v.1 |
| Modification:  | • Characteristics: Figures are updated |                    |  |                |
| BC817K_SER v.1 | 20171108                               |                    |  | -              |

## 12 Legal information

### 12.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

### 12.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

### 12.3 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia. In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation

**Terms and conditions of commercial sale** — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nexperia.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Suitability for use in automotive applications** — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

## 12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## Contents

|           |                                      |           |
|-----------|--------------------------------------|-----------|
| <b>1</b>  | <b>Product profile .....</b>         | <b>1</b>  |
| 1.1       | General description .....            | 1         |
| 1.2       | Features and benefits .....          | 1         |
| 1.3       | Applications .....                   | 1         |
| 1.4       | Quick reference data .....           | 2         |
| <b>2</b>  | <b>Pinning information .....</b>     | <b>2</b>  |
| <b>3</b>  | <b>Ordering information .....</b>    | <b>2</b>  |
| <b>4</b>  | <b>Marking .....</b>                 | <b>3</b>  |
| <b>5</b>  | <b>Limiting values .....</b>         | <b>3</b>  |
| <b>6</b>  | <b>Thermal characteristics .....</b> | <b>5</b>  |
| <b>7</b>  | <b>Characteristics .....</b>         | <b>7</b>  |
| <b>8</b>  | <b>Test information .....</b>        | <b>19</b> |
| 8.1       | Quality information .....            | 19        |
| <b>9</b>  | <b>Package outline .....</b>         | <b>20</b> |
| <b>10</b> | <b>Soldering .....</b>               | <b>20</b> |
| <b>11</b> | <b>Revision history .....</b>        | <b>21</b> |
| <b>12</b> | <b>Legal information .....</b>       | <b>22</b> |

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Nexperia B.V. 2018.

All rights reserved.

For more information, please visit: <http://www.nexperia.com>

For sales office addresses, please send an email to: [salesaddresses@nexperia.com](mailto:salesaddresses@nexperia.com)

Date of release: 6 March 2018

Document identifier: BC817K\_SER